

TOSHIBA Photocoupler Photorelay

# TLP202A

Telecommunications

Measurement and Control Equipment

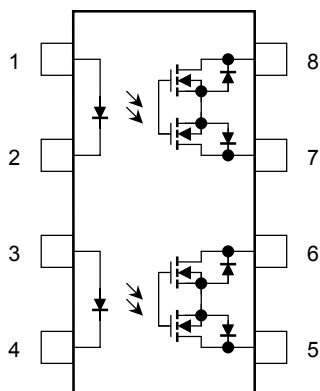
Data Acquisition System

Measurement Equipment

The Toshiba TLP202A consists of a gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET in an 8-pin SOP package. This photorelay has higher output current rating than phototransistor-type photocoupler; hence, it is suitable for use as On/Off control for high current.

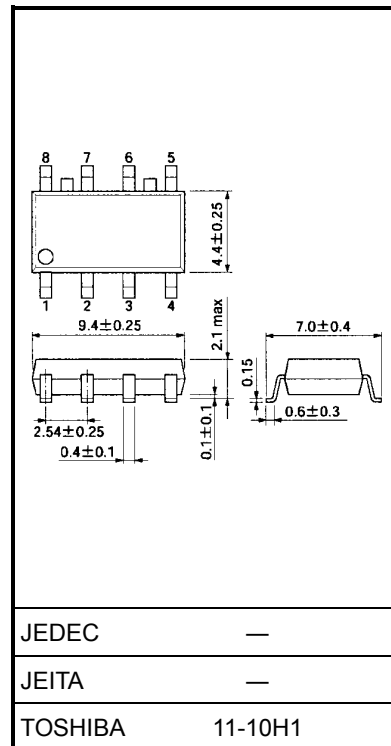
- 8-pin SOP (2.54SOP8): Height = 2.1 mm, pitch = 2.54 mm
- Normally open (1-form-A) device
- Peak off-state voltage: 60 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 400 mA (max)
- On-state resistance: 2  $\Omega$  (max)
- Isolation voltage: 1500 Vrms (min)
- UL recognized: UL1557, File No.E67349

## Pin Configuration (top view)



- 1, 3 : Anode
- 2, 4 : Cathode
- 5 : Drain D1
- 6 : Drain D2
- 7 : Drain D3
- 8 : Drain D4

Unit: mm



Weight: 0.2 g (typ.)

## Maximum Rating (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
LED	Forward current	$I_F$	50	mA
	Forward current derating (Ta $\geq$ 25°C)	$\Delta I_F/^\circ\text{C}$	-0.5	mA/°C
	Peak forward current (100 $\mu\text{s}$ pulse, 100 pps)	$I_{FP}$	1	A
	Reverse voltage	$V_R$	5	V
	Junction temperature	$T_j$	125	°C
Detector	Off-state output terminal voltage	$V_{OFF}$	60	V
	On-state current	$I_{ON}$	400	mA
	Forward current derating (Ta $\geq$ 25°C)	$\Delta I_{ON}/^\circ\text{C}$	-4.0	mA/°C
	Junction temperature	$T_j$	125	°C
Storage temperature		$T_{stg}$	-55 to 125	°C
Operating temperature		$T_{opr}$	-40 to 85	°C
Lead soldering temperature (10 s)		$T_{sol}$	260	°C
Isolation voltage (AC, 1 min, R.H. $\leq$ 60%) (Note 1)		$BV_S$	1500	Vrms

Note 1: LED pins are shorted together. Detector pins are also shorted together.

## Recommended Operating Conditions

Characteristics	Symbol	Min	Typ.	Max	Unit
Supply voltage	$V_{DD}$	—	—	48	V
Forward current	$I_F$	5	7.5	25	mA
On-state current	$I_{ON}$	—	—	400	mA
Operating temperature	$T_{opr}$	-20	—	65	°C

## Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Forward voltage	$V_F$	$I_F = 10\text{ mA}$	1.0	1.15	1.3	V
	Reverse current	$I_R$	$V_R = 5\text{ V}$	—	—	10	$\mu\text{A}$
	Capacitance	$C_T$	$V = 0, f = 1\text{ MHz}$	—	30	—	pF
Detector	Off-state current	$I_{OFF}$	$V_{OFF} = 60\text{ V}$	—	—	1	$\mu\text{A}$
	Capacitance	$C_{OFF}$	$V = 0, f = 1\text{ MHz}$	—	130	—	pF

## Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Trigger LED current	$I_{FT}$	$I_{ON} = 400\text{ mA}$	—	1.6	3	mA
Return LED current	$I_{FC}$	$I_{OFF} = 100\text{ }\mu\text{A}$	0.1	—	—	mA
On-state resistance	$R_{ON}$	$I_{ON} = 400\text{ mA}, I_F = 5\text{ mA}$	—	1	2	$\Omega$

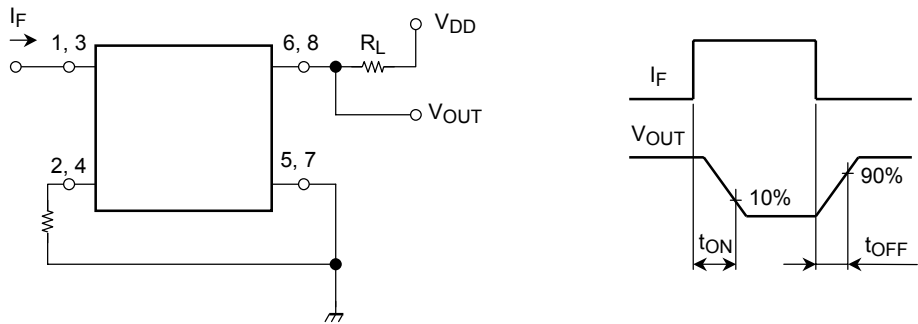
Isolation Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Capacitance input to output	CS	VS = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	RS	VS = 500 V, R.H. ≤ 60%	$5 \times 10^{10}$	$10^{14}$	—	Ω
Isolation voltage	BVS	AC, 1 min	1500	—	—	Vrms
		AC, 1 s, in oil	—	3000	—	
		DC, 1 min, in oil	—	3000	—	Vdc

Switching Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Turn-on time	tON	RL = 200 Ω (Note 2)	—	0.8	2	ms
Turn-off time	tOFF	VDD = 20 V, IF = 5 mA	—	0.1	0.5	

Note 2: Switching time test circuit



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